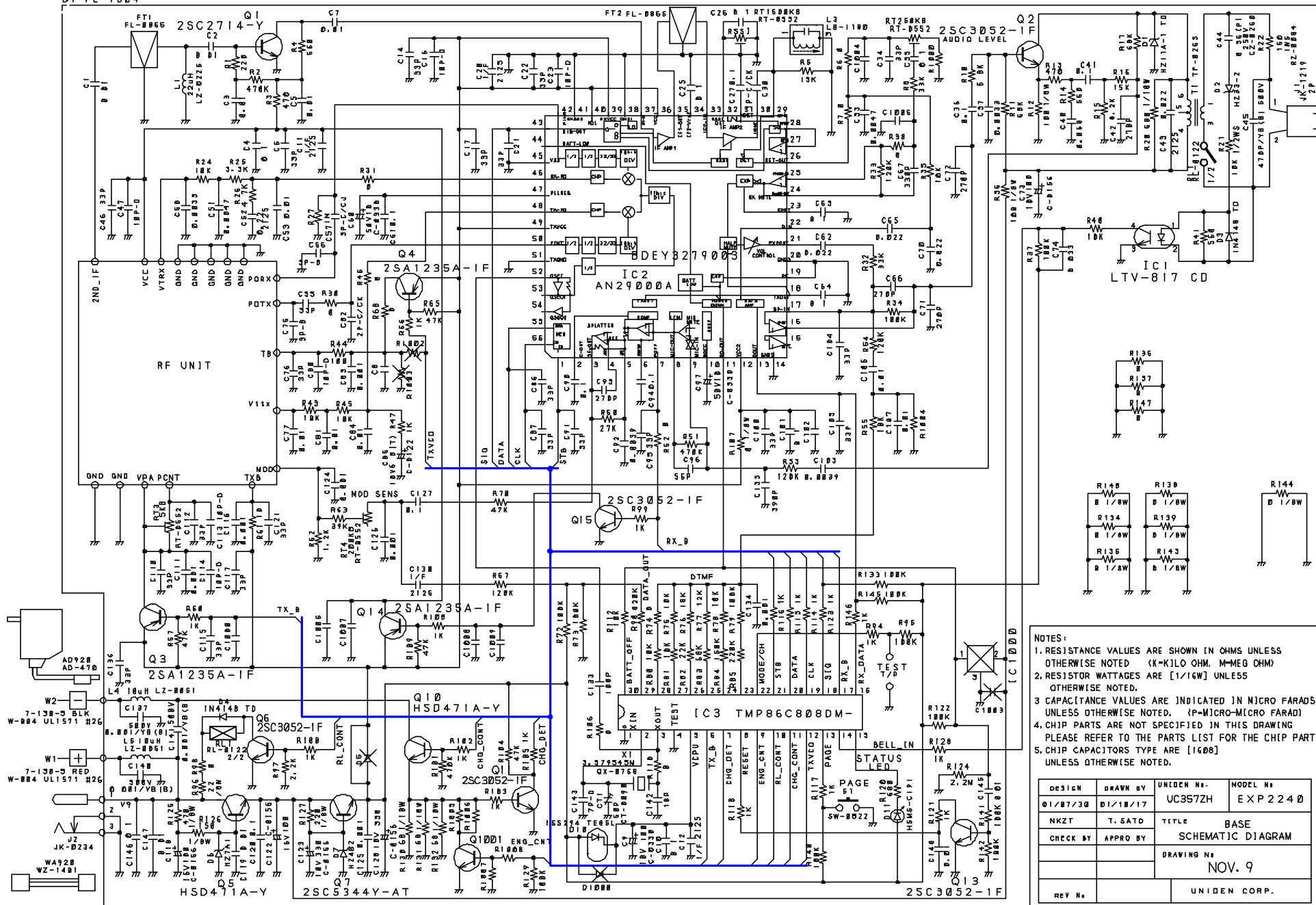
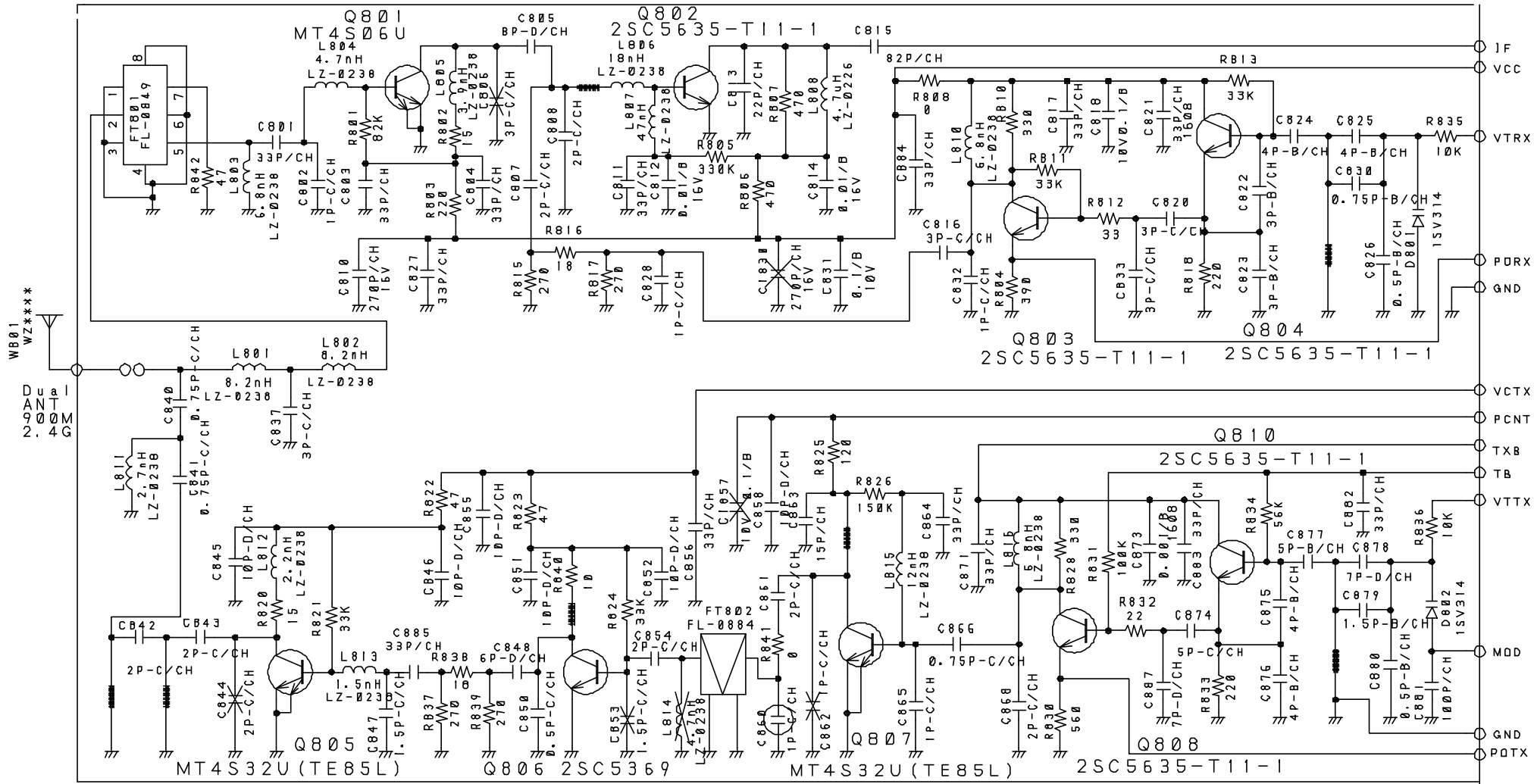




- NOTES:
1. RESISTANCE VALUES ARE SHOWN IN OHMS UNLESS OTHERWISE NOTED. (K=KILO OHM, M=MEG OHM)
 2. RESISTOR WATTAGES ARE [1/16W] UNLESS OTHERWISE NOTED.
 3. CAPACITANCE VALUES ARE INDICATED IN MICRO FARADS UNLESS OTHERWISE NOTED. (P=PICO-MICRO FARAD)
 4. CHIP PARTS ARE NOT SPECIFIED IN THIS DRAWING PLEASE REFER TO THE PARTS LIST FOR THE CHIP PARTS
 5. CHIP CAPACITORS TYPE ARE [1608] UNLESS OTHERWISE NOTED.

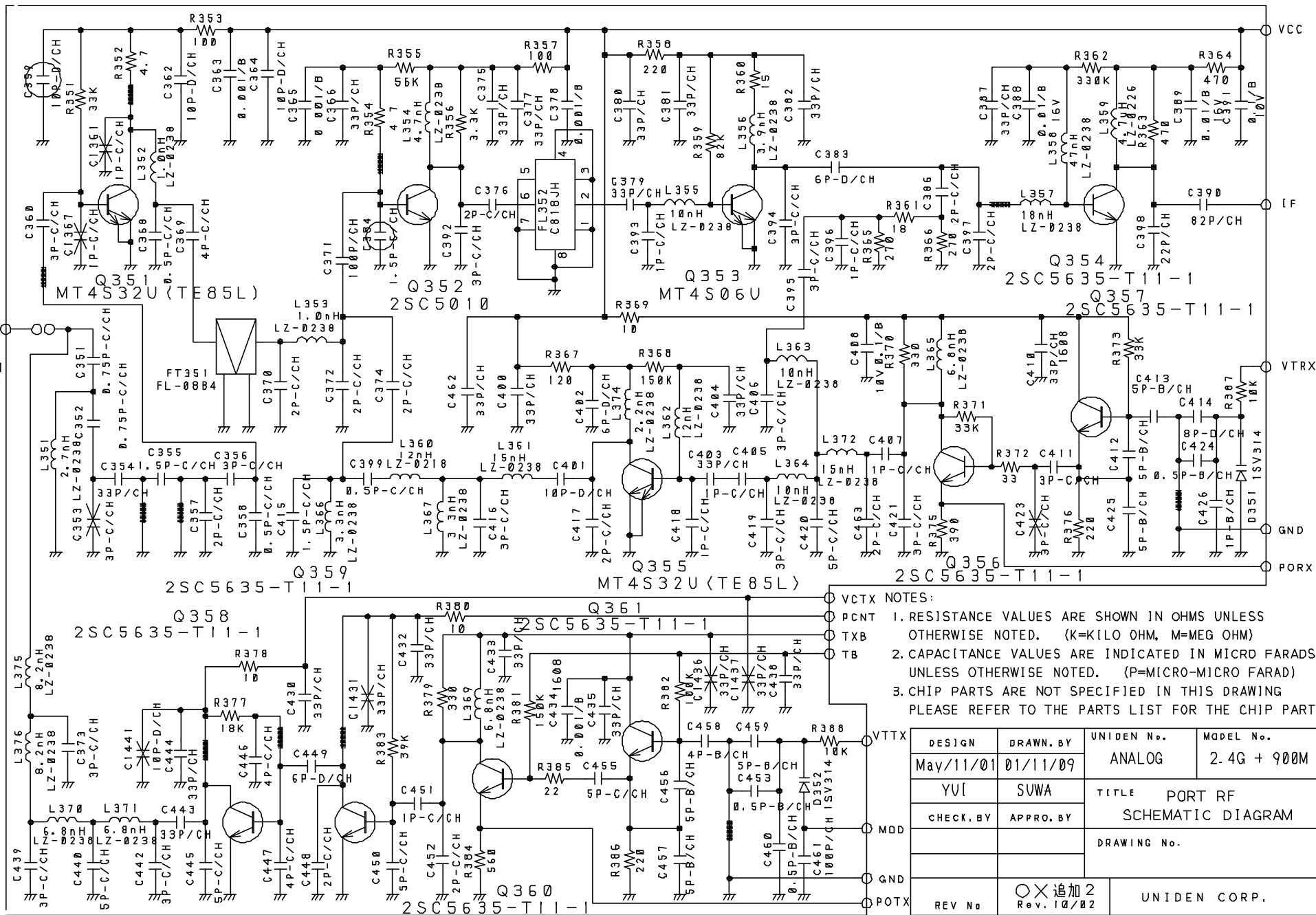
DESIGN	DRAWN BY	UNIDEN No.	MODEL No.
01/07/30	D1/18/17	UC357ZH	EXP 224 D
NKZT	T. SATO	TITLE BASE	
CHECK BY	APPRO BY	SCHEMATIC DIAGRAM	
		DRAWING No.	
		NOV. 9	
REV No.			UNIDEN CORP.



NOTES:

1. RESISTANCE VALUES ARE SHOWN IN OHMS UNLESS OTHERWISE NOTED. (K=KILO OHM, M=MEG OHM)
2. RESISTOR WATTAGES ARE [1/16W (1005)] UNLESS OTHERWISE NOTED.
3. CAPACITANCE VALUES ARE INDICATED IN MICRO FARADS UNLESS OTHERWISE NOTED. (P=MICRO-MICRO FARAD)
4. CHIP PARTS ARE NOT SPECIFIED IN THIS DRAWING PLEASE REFER TO THE PARTS LIST FOR THE CHIP PARTS.
5. CHIP CAPACITORS TYPE ARE [1005] UNLESS OTHERWISE NOTED.

DESIGN	DRAWN BY	UNIDEN No.	MODEL No.
May/14/01	01/11/09	ANALOG	2.4G + 900M
YU1	SUWA	TITLE BASE RF SCHEMATIC DIAGRAM	
CHECK BY	APPRO BY		
		DRAWING No.	
REV. No.	○×追加 Rev 10/02		UNIDEN CORP.



CONTEXT NOTES:

1. RESISTANCE VALUES ARE SHOWN IN OHMS UNLESS OTHERWISE NOTED. {K=KILO OHM, M=MEG OHM}
2. CAPACITANCE VALUES ARE INDICATED IN MICRO FARADS UNLESS OTHERWISE NOTED. {P=MICRO-MICRO FARAD}
3. CHIP PARTS ARE NOT SPECIFIED IN THIS DRAWING PLEASE REFER TO THE PARTS LIST FOR THE CHIP PARTS.

X	DESIGN	DRAWN BY	UNIDEN No.	MODEL No.
	May/11/01	01/11/09	ANALOG	2-4G + 900M
	YUI	SUWA	TITLE PORT RF	
	CHECK BY	APPRO. BY	SCHEMATIC DIAGRAM	
D			DRAWING No.	
D				
X	REV No	○×追加2 Rev. 10/02	UNIDEN CORP.	